DS1666, DS1666 Audio Digital Resisto
GNMENT
$\begin{array}{c c c c c c c c c c c c c c c c c c c $
NC         5         12         VH           CS         6         11         NC           NC         7         10         NC           SND         8         9         VL           16-PIN SOIC (300 MIL) See Mech. Drawings Section         Section
<ul> <li>High Terminal of Resistor</li> <li>Low Terminal of Resistor</li> <li>Wiper Terminal of Resistor</li> <li>Up/Down Control</li> <li>Wiper Movement Control</li> <li>Chip Select for Wiper Moveme</li> </ul>

position of the wiper on the resistance array is controlled

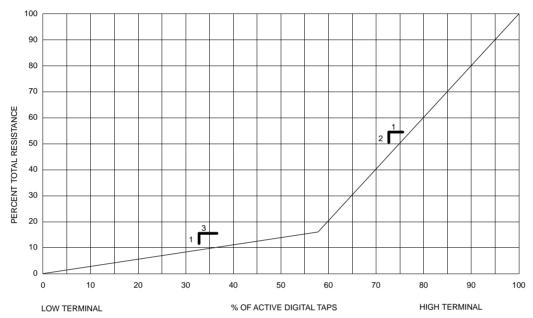
by the  $\overline{CS}$ , U/D and  $\overline{INC}$  inputs. The position of the wiper

defaults to the 10% position on power up. The resolu-

tion of the DS1666 is shown in Figure 1.

3% of scale advances 1% of total resistance for each ition of low volume signals. The upper half of the potentiometer advances 2% of resistance for every 1% of scale advanced, providing for the lower resolution gain required for high volume amplification.





#### GRAPH OF AUDIO TAPER Figure 1

#### OPERATION

The  $\overline{CS}$ , U/D and  $\overline{INC}$  inputs control the position of the wiper along the resistor array (Figure 1). When  $\overline{CS}$  is active (low), a high to low transition on the INC will increment or decrement an internal counter depending on the level of the  $U/\overline{D}$  pin. When the  $U/\overline{D}$  pin is low, the counter will decrement. When the  $U/\overline{D}$  pin is high, the counter will increment. The state of the  $U/\overline{D}$  pin can be changed while CS is active allowing for precise adjustment during calibration. The output of the counter is decoded to set the position of the wiper. When the  $\overline{CS}$  input transitions to the high (inactive) level, the value of the counter is stored and the wiper position is maintained until power ( $V_{CC}$ ) is lost. When power is restored, the DS1666 returns to the default setting and positions the wiper to 10 percent. The value of the end-to-end and end-to-wiper position is indeterminate while V<sub>CC</sub> is not applied.

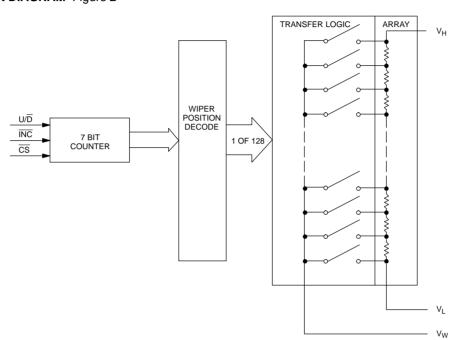
The DS1666 has a resistor array that resembles an audio taper potentiometer as shown in Figure 1 1. Since the taper is not linear, exact resistance values for each of the 128 positions of the resistor is not specified. However, the end-to-end resistance is specified to be within  $\pm 20$  percent of the stated resistor value over an industrial temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C.

#### ANALOG CHARACTERISTICS

End-to-End Resistance Tolerance =  $\pm 20$  percent Typical Noise = <120 dB/Hz REF:IV Temperature Coefficient =  $\pm 800$  PPM/°C typical Resistance at tap #74=18%  $\pm 2\%$  of total resistance.

#### **PIN DESCRIPTIONS**

- V<sub>H</sub> The high end of the potentiometer. This terminal is capable of handling input voltages between ±5 volts.
- V<sub>L</sub> The Low end of the potentiometer. This terminal is capable of handling input voltages between ±5 volts.
- $V_W \qquad \begin{array}{l} \text{The wiper terminal of the potentiometer.} \\ \text{The value of the wiper is controlled by the} \\ U/\overline{D} \text{ and the }\overline{INC} \text{ pins.} \end{array}$
- Increment Toggling INC will move the potentiometer wiper by either incrementing or decrementing the counter.



# BLOCK DIAGRAM Figure 2

# MODE SELECTION Figure 3

CS	INC	U/D	MODE
L		Н	WIPER UP
L		L	WIPER DOWN
	Н	Х	STORE WIPER POSITION

#### **ABSOLUTE MAXIMUM RATINGS\***

Voltage on $\overline{CS}$ , $\overline{INC}$ , U/ $\overline{D}$ , and V <sub>CC</sub> Relative to Ground	-0.5V to +7.0V
Voltage on V <sub>H</sub> , V <sub>L</sub> , and V <sub>W</sub> Relative to Ground	-6.5V to +6.5V
Voltage on V <sub>B</sub>	–6.5V to Ground
Operating Temperature	–40°C to +85°C
Storage Temperature	–55°C to +125°C
Soldering Temperature	260°C for 10 seconds

\* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS						(–40°C to +85°C)	
PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES	
Supply Voltage	V <sub>CC</sub>	+4.5	5.0	5.5	V	1	
Input Logic 1	V <sub>IH</sub>	2.0		V <sub>CC</sub> +0.5	V	1	
Input Logic 0	V <sub>IL</sub>	-0.5		+0.8	V	1	
V <sub>H</sub> , V <sub>L</sub> , V <sub>W</sub> Voltage	V <sub>R</sub>	V <sub>B</sub> -0.3		V <sub>CC</sub> +0.3	V	1	
V <sub>B</sub> Voltage	VB	-5.5		GND	V	1	

#### DC ELECTRICAL CHARACTERISTICS

 $(-40^{\circ}\text{C to } +85^{\circ}\text{C}; \text{ V}_{\text{CC}} = 5.0\text{V} \pm 10\%)$ 

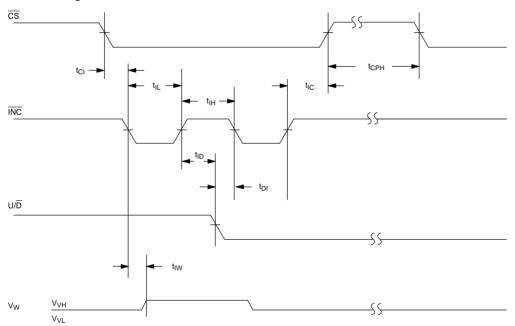
PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES
Supply Current	I <sub>CC</sub>		0.1	5	mA	3
Input Leakage	ILI	-1		+1	μA	2
Wiper Resistance	R <sub>W</sub>		350	650	Ω	
Wiper Current	I <sub>W</sub>			1	mA	3

## CAPACITANCE

CAPACITANCE (t <sub>A</sub> = 2							)
PARAMETER	SYMBOL	CONDITION	ТҮР	MAX	UNITS	NOTES	
Capacitance	C <sub>IN</sub>	t <sub>A</sub> =25°C	6	10	pF	2	

AC ELECTRICAL CHARACTERISTICS			(t <sub>A</sub> =–40°C to +85°C; V <sub>CC</sub> =+5V $\pm$ 10%)			
PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES
CS to INC Setup	t <sub>CI</sub>	100			ns	
INC High to U/D Change	t <sub>ID</sub>	100			ns	
U/D to INC Setup	t <sub>DI</sub>	1			μs	
INC Low Period	t <sub>IL</sub>	500			ns	
INC High Period	t <sub>IH</sub>	1			μs	
$\overline{\text{INC}}$ Inactive to $\overline{\text{CS}}$ Inactive	t <sub>IC</sub>	500			ns	
CS Deselect Time	t <sub>CPH</sub>	100			ns	

# AC TIMING Figure 4



## NOTES:

- 1. All voltages are referenced to ground.
- 2. This parameter is periodically sampled and not 100% tested.
- 3. Typical values are for  $t_{A}$  = 25°C and nominal supply voltages.
- 4. Wiper output open circuited.

# AC TEST CONDITIONS

Input Pulse Levels	0V to 3V
Input Rise and Fall Times	10 ns
Input Level	1.5V

#### DS1666 ORDERING INFORMATION

ORDERING NUMBER	PACKAGE	OPERATING TEMPERATURE	VERSION
DS1666–010	14L DIP	–40°C TO +85°C	10ΚΩ
DS1666-050	14L DIP	–40°C TO +85°C	50ΚΩ
DS1666-100	14L DIP	–40°C TO +85°C	100ΚΩ
DS1666S-010	16L SOIC (300 MIL)	–40°C TO +85°C	10ΚΩ
DS1666S-050	16L SOIC (300 MIL)	–40°C TO +85°C	50ΚΩ
DS1666S-100	16L SOIC (300 MIL)	–40°C TO +85°C	100ΚΩ

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#### DATA SHEET REVISION SUMMARY

The following represent the key differences between 07/26/93 and 06/18/97 version of the DS1666 data sheet. Please review this summary carefully.

- 1. Remove commercial temp grade reference
- 2. Add order info table